



Micron Technology



Part Number:	MT29RZ4B2DZZHGSK-18 W.80E
Manufacturer/Brand:	Micron Technology
Product description	IC FLASH RAM 4G PARALLEL 533MHZ
Datasheets:	
RoHs Status	 Lead free / RoHS Compliant
Ship From	Hong Kong
Shipment Way	DHL/Fedex/TNT/UPS/EMS

REQUEST FOR QUOTATION

Image may be representation. See specifications for product details.

Specifications of MT29RZ4B2DZZHGSK-18 W.80E

PART NUMBER	MT29RZ4B2DZZHGSK-18 W.80E
MANUFACTURER	Micron Technology
DESCRIPTION	IC FLASH RAM 4G PARALLEL 533MHZ
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
DATA SHEET	
WRITE CYCLE TIME - WORD, PAGE	-
VOLTAGE - SUPPLY	1.8V
TECHNOLOGY	FLASH - NAND, DRAM - LPDDR2
SERIES	-
OTHER NAMES	MT29RZ4B2DZZHGSK-18 W.80E-ND MT29RZ4B2DZZHGSK-18W.80E
OPERATING TEMPERATURE	-25°C ~ 85°C (TA)
MOISTURE SENSITIVITY LEVEL (MSL)	3 (168 Hours)
MEMORY TYPE	Non-Volatile
MEMORY SIZE	4Gb (512M x 8)(NAND), 2G (64M x 32)(LPDDR2)
MEMORY INTERFACE	Parallel
MEMORY FORMAT	FLASH, RAM
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
DETAILED DESCRIPTION	FLASH - NAND, DRAM - LPDDR2 Memory IC 4Gb (512M x 8)(NAND), 2G (64M x 32)(LPDDR2) Parallel 533MHz
CLOCK FREQUENCY	533MHz

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